

# Study piezoelectric properties of GaN nanowires by AFM characterizations



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GaN nanowires (NWs) are promissing candidates for piezoelectric nano-generators thanks to their advantages:

- Lead-free material ullet
- High thermal, chemical stability and radiation hardness  $\bullet$
- High force sensitivity thanks to large degree of elastic deformation
- Surface charge effect<sup>1</sup> potentially enhance piezoelectric efficiency

Context

However, the piezoelectric properties of NW are not fully investigated due to the challenge of performing characterizations at the nanoscale

 $\rightarrow$  In this work: Study the piezoelectric properties of each individual GaN NWs using AFM (direct and inverse piezoelectric methods)

**Our objective:** Identify NWs with optimal piezoelectric properties to integrate into a polymer matrix for piezoelectric applications



## GaN NWs for AFM characterizations



Ti/Pt electrode



#### GaN NWs grown by PA-MBE

GaN NWs encapsulated in BCB



Metal electrode deposited on top of NWs



### AFM compression mode

260 nm



AFM tip: Multi75E-G

Normal force: 160 nN





V<sub>tip</sub> - V<sub>semp</sub>

Amplificator

asurem Resistor



*Evolution of piezoelectric output voltage as function of NW diameter.* 



*Evolution of piezo-conversion efficiency as function of NW diameter.*<sup>2</sup>

Best piezoelectric Response for a NW diameter of around 45 nm thanks to the surface charge effects

How are evolving the piezoelectric coefficient as a function of the NW diameter? Which influence of the surface charge effects?

Datacube Piezoelectric Force Microscopy (PFM)







- Piezoresponse amplitude is proportional to the piezoelectric coefficient  $d_{33}$
- Piezoresponse phase is attibuted to the piezoelectric polarity







2 µm AFM tip: Multi75E-G Normal force: 100 nN Applied Voltage: 2 V – 330 kHz

-120 High signal-to-noise piezo responses, but need a reference sample for quantity measurement.

## Conclusion

- Measured directly the piezoelectric voltage of individual NWs
- Bending and compression modes show the same optimal diameter
- Measured piezoelectric responses of individual NWs by datacube PFM

**Perspective:** Establish a protocol for PFM measurements and piezoelectric coefficient evaluation

References: [1] R. Calarco et al., J. Mater. Res. 26, 2157 (2011); [2] N. Gogneau et al., Nanoscale 14, 4965 (2022).

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